

# SOLAR CELL DEVICE PHYSICS

Second Edition

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# Contents

|                                                     |              |
|-----------------------------------------------------|--------------|
| <b>Preface.....</b>                                 | <b>xi</b>    |
| <b>Acknowledgments .....</b>                        | <b>xiii</b>  |
| <b>List of Symbols .....</b>                        | <b>xv</b>    |
| <b>List of Abbreviations.....</b>                   | <b>xxvii</b> |
| <br>                                                |              |
| <b>1     Introduction.....</b>                      | <b>1</b>     |
| 1.1 Photovoltaic Energy Conversion .....            | 1            |
| 1.2 Solar Cells and Solar Energy Conversion.....    | 2            |
| 1.3 Solar Cell Applications .....                   | 7            |
| References .....                                    | 8            |
| <br>                                                |              |
| <b>2     Material Properties and Device Physics</b> |              |
| <b>Basic to Photovoltaics .....</b>                 | <b>9</b>     |
| 2.1 Introduction .....                              | 9            |
| 2.2 Material Properties .....                       | 10           |
| 2.2.1 Structure of solids.....                      | 10           |
| 2.2.2 Phonon spectra of solids .....                | 13           |
| 2.2.3 Electron energy levels in solids .....        | 18           |
| 2.2.4 Optical phenomena in solids.....              | 28           |
| 2.2.5 Carrier recombination and trapping.....       | 36           |
| 2.2.6 Photocarrier generation.....                  | 45           |
| 2.3 Transport.....                                  | 46           |
| 2.3.1 Transport processes in bulk solids .....      | 46           |
| 2.3.2 Transport processes at interfaces .....       | 53           |
| 2.3.3 Continuity concept.....                       | 58           |
| 2.3.4 Electrostatics.....                           | 60           |
| 2.4 The Mathematical System .....                   | 60           |
| 2.5 Origins of Photovoltaic Action .....            | 63           |
| References .....                                    | 64           |
| <br>                                                |              |
| <b>3     Structures, Materials, and Scale.....</b>  | <b>67</b>    |
| 3.1 Introduction .....                              | 67           |

|       |                                                                         |     |
|-------|-------------------------------------------------------------------------|-----|
| 3.2   | Basic Structures for Photovoltaic Action.....                           | 69  |
| 3.2.1 | General comments on band diagrams.....                                  | 69  |
| 3.2.2 | Photovoltaic action arising from built-in<br>electrostatic fields ..... | 73  |
| 3.2.3 | Photovoltaic action arising from diffusion .....                        | 83  |
| 3.2.4 | Photovoltaic action arising from<br>effective fields.....               | 85  |
| 3.2.5 | Summary of practical structures.....                                    | 92  |
| 3.3   | Key Materials.....                                                      | 95  |
| 3.3.1 | Absorber materials.....                                                 | 95  |
| 3.3.2 | Contact materials .....                                                 | 102 |
| 3.4   | Length Scale Effects for Materials and Structures .....                 | 107 |
| 3.4.1 | The role of scale in absorption and<br>collection .....                 | 107 |
| 3.4.2 | Using the nano-scale to capture lost energy .....                       | 115 |
| 3.4.3 | The role of scale in light management.....                              | 116 |
|       | References .....                                                        | 117 |

|          |                                                                       |            |
|----------|-----------------------------------------------------------------------|------------|
| <b>4</b> | <b>Homojunction Solar Cells .....</b>                                 | <b>121</b> |
| 4.1      | Introduction .....                                                    | 121        |
| 4.2      | Overview of Homojunction Solar Cell<br>Device Physics.....            | 124        |
| 4.2.1    | Transport.....                                                        | 124        |
| 4.2.2    | The homojunction barrier region.....                                  | 131        |
| 4.3      | Analysis of Homojunction Device Physics:<br>Numerical Approach.....   | 132        |
| 4.3.1    | Basic p–n homojunction .....                                          | 133        |
| 4.3.2    | Addition of a front HT-EBL .....                                      | 141        |
| 4.3.3    | Addition of a front HT-EBL and back<br>ET-HBL .....                   | 145        |
| 4.3.4    | Addition of a front high-low junction.....                            | 149        |
| 4.3.5    | A p–i–n cell with a front HT-EBL and<br>back ET-HBL.....              | 154        |
| 4.3.6    | A p–i–n cell using a poor $\mu\tau$ absorber.....                     | 155        |
| 4.4      | Analysis of Homojunction Device Physics:<br>Analytical Approach ..... | 166        |
| 4.4.1    | Basic p–n homojunction .....                                          | 167        |
| 4.5      | Some Homojunction Configurations .....                                | 179        |
|          | References .....                                                      | 181        |

|              |                                                                          |                |
|--------------|--------------------------------------------------------------------------|----------------|
| <b>5</b>     | <b>Semiconductor–semiconductor Heterojunction Cells.....</b>             | <b>183</b>     |
| 5.1          | Introduction .....                                                       | 183            |
| 5.2          | Overview of Heterojunction Solar Cell Device Physics.....                | 189            |
| 5.2.1        | Transport.....                                                           | 189            |
| 5.2.2        | The heterojunction barrier region .....                                  | 193            |
| 5.3          | Analysis of Heterojunction Device Physics:<br>Numerical Approach.....    | 202            |
| 5.3.1        | Absorption by free electron–hole pair<br>excitations .....               | 203            |
| 5.3.2        | Absorption by exciton generation.....                                    | 237            |
| 5.4          | Analysis of Heterojunction Device Physics:<br>Analytical Approach .....  | 247            |
| 5.4.1        | Absorption by free electron–hole<br>excitations .....                    | 247            |
| 5.4.2        | Absorption by excitons .....                                             | 259            |
| 5.5          | Some Heterojunction Configurations .....                                 | 259            |
|              | References .....                                                         | 261            |
| <br><b>6</b> | <br><b>Surface-barrier Solar Cells.....</b>                              | <br><b>263</b> |
| 6.1          | Introduction .....                                                       | 263            |
| 6.2          | Overview of Surface-barrier Solar Cell<br>Device Physics.....            | 268            |
| 6.2.1        | Transport.....                                                           | 268            |
| 6.2.2        | The surface-barrier region .....                                         | 271            |
| 6.3          | Analysis of Surface-barrier Device Physics:<br>Numerical Approach.....   | 273            |
| 6.4          | Analysis of Surface-barrier Device Physics:<br>Analytical Approach ..... | 283            |
| 6.5          | Some Surface-barrier Configurations .....                                | 291            |
|              | References .....                                                         | 293            |
| <br><b>7</b> | <br><b>Dye-sensitized Solar Cells .....</b>                              | <br><b>295</b> |
| 7.1          | Introduction .....                                                       | 295            |
| 7.2          | Overview of Dye-sensitized Solar Cell<br>Device Physics.....             | 297            |
| 7.2.1        | Transport.....                                                           | 297            |
| 7.2.2        | The dye-sensitized solar cell barrier region.....                        | 300            |
| 7.3          | Analysis of DSSC Device Physics:<br>Numerical Approach.....              | 301            |

|                                                                                                                                              |            |
|----------------------------------------------------------------------------------------------------------------------------------------------|------------|
| 7.4 Some DSSC Configurations .....                                                                                                           | 307        |
| References .....                                                                                                                             | 308        |
| <b>Appendix A: The Absorption Coefficient.....</b>                                                                                           | <b>311</b> |
| <b>Appendix B: Radiative Recombination.....</b>                                                                                              | <b>313</b> |
| <b>Appendix C: Shockley-Read-Hall (Gap-state-assisted)<br/>Recombination.....</b>                                                            | <b>317</b> |
| <b>Appendix D: Conduction- and Valence-band Transport.....</b>                                                                               | <b>325</b> |
| <b>Appendix E: The Quasi-neutral-region Assumption and<br/>Lifetime Semiconductors .....</b>                                                 | <b>335</b> |
| <b>Appendix F: Determining <math>p(x)</math> and <math>n(x)</math> for the Space-<br/>charge-neutral Regions of a Homojunction .....</b>     | <b>339</b> |
| <b>Appendix G: Determining <math>n(x)</math> for the Space-charge-neutral<br/>Region of a Heterojunction p-type Bottom<br/>Material.....</b> | <b>343</b> |
| <b>Index.....</b>                                                                                                                            | <b>347</b> |